



Trn 2814

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Vishnu K. Agarwal et al.
Title: TRANSISTOR STRUCTURE HAVING REDUCED TRANSISTOR LEAKAGE
ATTRIBUTES

Docket No.: 303.780US1
Filed: January 17, 2002
Examiner: Hoai V Pham

Serial No.: 10/053,300
Due Date: January 28, 2006
Group Art Unit: 2814

MS Amendment

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

We are transmitting herewith the following attached items (as indicated with an "X"):

Return postcard.
 Amendment and Response (18 pgs.).
 Supplemental Information Disclosure Statement (2 pgs.), Form 1449 (1 pg.).
 Check in the amount of \$180.00 to cover the fee for consideration of Information Disclosure Statement under 97(c).

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CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: MS Amendment, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 9 day of January, 2006.

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